

<u>捷多邦, 专业PCB打样工厂, 24小时加急出货</u> HMC429LP4

MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz

Typical Applications

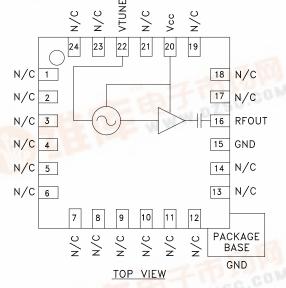
Low noise MMIC VCO w/Buffer Amplifier for:

- 802.11a, HiperLAN WLAN
- VSAT, UNII & Microwave Radio
- Test Equipment & Industrial Controls
- Military

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VCOs - SM

Functional Diagram



Features

Pout: +4.0 dBm Phase Noise: -105 dBc/Hz @100 KHz No External Resonator Needed Single Supply: 3V @ 30 mA QFN Leadless SMT Package, 16 mm²

General Description

The HMC429LP4 is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCO with integrated resonator, negative resistance device, varactor diode, and buffer amplifier. Covering 4.45 to 5.0 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.0 dBm typical from a single supply of 3.0V @ 30mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4 x 4 mm surface mount package.

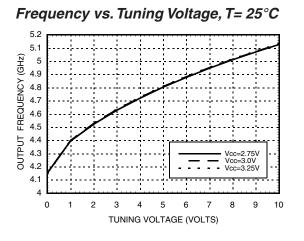
Parameter	Min.	Тур.	Max.	Units
Frequency Range	ency Range 4.45 - 5.0		-17	GHz
Power Output	1.0	4.0	8-5-11	dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output	m lit	-105	WWW.W.	dBc/Hz
Tune Voltage (Vtune)	0	L	10	V
Supply Current (Icc) (Vcc = +3.0V)		30		mA
Tune Port Leakage Current			10	μA
Output Return Loss		6		dB
Harmonics 2nd 3rd		-11 -23		dBc dBc
Pulling (into a 2.0:1 VSWR)		10		MHz pp
Pushing @ Vtune= +5V		14		MHz/V
Frequency Drift Rate		0.4		MHz/°C

Electrical Specifications, T₄ = +25° C, Vcc = +3V

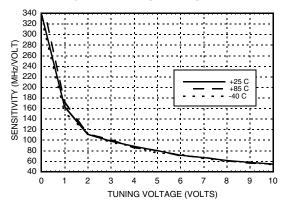
For price, delivery, and to place orders, please contact Hittite Microwave Corporation



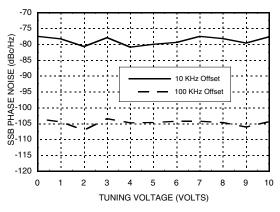
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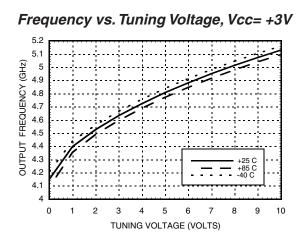


Sensitivity vs. Tuning Voltage, Vcc= +3V

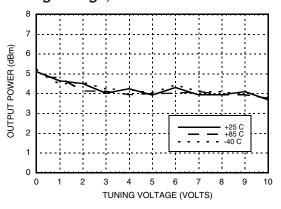


Phase Noise vs. Tuning Voltage

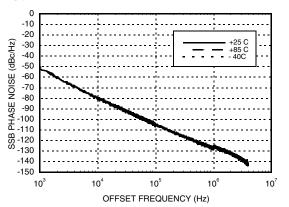




Output Power vs. Tuning Voltage, Vcc= +3V



Typical SSB Phase Noise @ Vtune= +5V





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Absolute Maximum Ratings

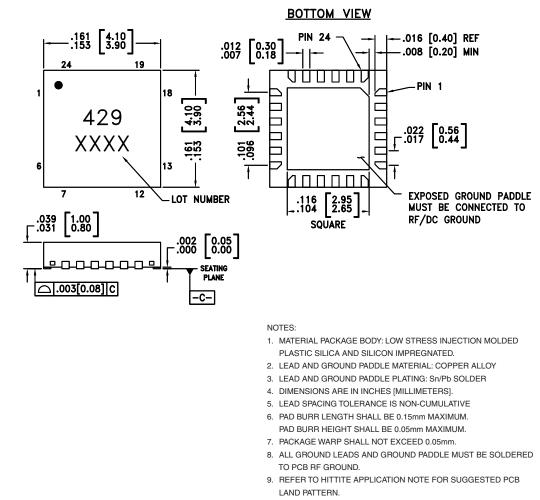
Vcc	+3.5 Vdc	
Vtune	0 to +11V	
Channel Temperature	135 °C	
Continuous Pdiss (T = 85°C) (derate 6.28 mW/°C above 85°C)	565 W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)	
2.75	21	
3.0	30	
3.25	38	

Note: VCO will operate over full voltage range shown above.

Outline Drawing





HMC429LP4 MMIC VCO w/ BUFFER AMPLIFIER, 4.45 - 5.0 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection	
15	GND	This pin must be connected to RF & DC ground.	
16	RFOUT	RF output (AC coupled)	
20	Vcc	Supply Voltage Vcc= 3V	Vcc O
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	VTUNE 0 5.2pF
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	

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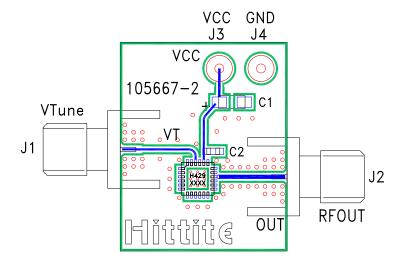
VCOs - SMT

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Evaluation PCB



List of Materials

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VCOs - SMT

Item	Description	
J1 - J2	PC Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	4.7 μF Tantalum Capacitor	
C2	10,000 pF Capacitor, 0603 Pkg.	
U1	HMC429LP4 VCO	
PCB*	105667 Eval Board	
* Circuit Board Material: Rogers 4350		

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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Notes:

VCOs - SMT

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